2-Input AND Gate with **Open Drain Output**

The MC74VHC1G09E is an advanced high speed CMOS 2-input AND gate with open drain output fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining CMOS low power dissipation.

The internal circuit is composed of three stages, including an open drain output which provides the capability to set output switching level. This allows the MC74VHC1G09E to be used to interface 5 V circuits to circuits of any voltage between V_{CC} and 5.5 V using an external resistor and power supply.

The MC74VHC1G09E input structure provides protection when voltages up to 5.5 V are applied, regardless of the supply voltage.

Features

- High Speed: $t_{PD} = 4.3 \text{ ns}$ (Typ) at $V_{CC} = 5 \text{ V}$
- Low Internal Power Dissipation: $I_{CC} = 1 \mu A$ (Max) at $T_A = 25^{\circ}C$
- Power Down Protection Provided on Inputs
- Pin and Function Compatible with Other Standard Logic Families
- Chip Complexity: FETs = 62; Equivalent Gates = 16
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

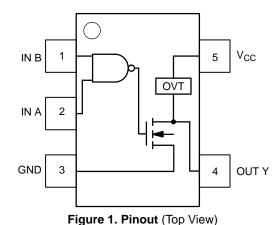




Figure 2. Logic Symbol



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MARKING DIAGRAMS



SC-88A / SOT-353 / SC-70 **DF SUFFIX CASE 419A**



VX = Device Code = Date Code*

= Pb-Free Package

(Note: Microdot may be in either location) *Date Code orientation and/or position may vary depending upon manufacturing location.

PIN ASSIGNMENT					
1	IN B				
2 IN A					
3	GND				
4	OUT Y				
5	V _{CC}				

FUNCTION TABLE

Inp	uts	Output
Α	В	Υ
L	L	L
L	Н	L
н	L	L
Н	Н	z

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

MAXIMUM RATINGS

Symbol	Characteristics	Value	Unit
V _{CC}	DC Supply Voltage	-0.5 to +6.5	V
V _{IN}	DC Input Voltage	-0.5 to +6.5	V
V _{OUT}	DC Output Voltage	-0.5 to +6.5	V
I _{IK}	Input Diode Current	-20	mA
I _{OK}	Output Diode Current	+20	mA
I _{OUT}	DC Output Current, per Pin	+25	mA
Icc	DC Supply Current, V _{CC} and GND	+50	mA
P _D	Power dissipation in still air	200	mW
θ_{JA}	Thermal resistance	333	°C/W
TL	Lead temperature, 1 mm from case for 10 s	260	°C
TJ	Junction temperature under bias	+150	°C
T _{stg}	Storage temperature	-65 to +150	°C
MSL	Moisture Sensitivity	Level 1	
F _R	Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
V _{ESD}	ESD Withstand Voltage Human Body Model (Note 1) Charged Device Model (Note 2)	4000 1000	V
I _{Latchup}	Latchup Performance Above V _{CC} and Below GND at 125°C (Note 3)	±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. Tested to EIA/JESD22-A114-A
- 2. Tested to JESD22-C101-A
- 3. Tested to EIA/JESD78

RECOMMENDED OPERATING CONDITIONS

Symbol	Characteristics	Min	Max	Unit
V _{CC}	DC Supply Voltage	2.0	5.5	V
V _{IN}	DC Input Voltage	0.0	5.5	V
V _{OUT}	DC Output Voltage	0.0	7.0	V
T _A	Operating Temperature Range	-55	+125	°C
t _r , t _f	Input Rise and Fall Time $ \begin{array}{c} V_{CC} = 3.3 \ V \pm 0.3 \ V \\ V_{CC} = 5.0 \ V \pm 0.5 \ V \end{array} $	0	10 5	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

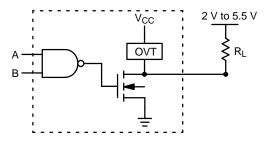
			v _{cc}	7	Γ _A = 25°0	;	$T_A \le$	85°C	-55 ≤ T _A	≤ 125°C	
Symbol	Parameter	Test Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
V _{IH}	Minimum High-Level Input Voltage		2.0 3.0 4.5 5.5	1.5 2.1 3.15 3.85			1.5 2.1 3.15 3.85		1.5 2.1 3.15 3.85		V
V _{IL}	Maximum Low-Level Input Voltage		2.0 3.0 4.5 5.5			0.5 0.9 1.35 1.65		0.5 0.9 1.35 1.65		0.5 0.9 1.35 1.65	V
V _{OL}	Maximum Low-Level Output Voltage V _{IN} = V _{IH} or V _{IL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 50 \mu\text{A}$	2.0 3.0 4.5		0.0 0.0 0.0	0.1 0.1 0.1		0.1 0.1 0.1		0.1 0.1 0.1	V
		$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 4 \text{ mA}$ $I_{OL} = 8 \text{ mA}$	3.0 4.5			0.36 0.36		0.44 0.44		0.52 0.52	V
I _{IN}	Maximum Input Leakage Current	V _{IN} = 5.5 V or GND	0 to 5.5			±0.1		±1.0		±1.0	μΑ
Icc	Maximum Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	5.5			1.0		20		40	μΑ
I _{OFF}	Power Off-Output Leakage Current	V _{OUT} = 5.5 V V _{IN} = 5.5 V	0			0.25	_	2.5		5	μΑ

AC ELECTRICAL CHARACTERISTICS Input $t_f = t_f = 3.0 \text{ ns}$

			T _A = 25°C		T _A = 25°C		$T_A = 25^{\circ}C$		$T_A = 25^{\circ}C$ $T_A \le 85^{\circ}C$		-55 ≤ T _A ≤ 125°C		
Symbol	Parameter	Test Conditions	Min	Тур	Max	Min	Max	Min	Max	Unit			
t _{PZL}	Maximum Output Enable Time, Input A or B to Y	$ \begin{array}{c} V_{CC} = 3.3 \pm 0.3 \; V \; C_L = 15 \; pF \\ R_L = 1000 \; \Omega \qquad \qquad C_L = 50 \; pF \end{array} $		6.2 8.7	8.8 12.3		10.5 14.0		12.5 16.5	ns			
	input A or B to 1	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		4.3 5.8	5.9 7.9		7.0 9.0		9.0 11.0				
t _{PLZ}	Maximum Output Disable Time	$\begin{aligned} & \text{V}_{\text{CC}} = 3.3 \pm 0.3 \text{ V C}_{\text{L}} = 50 \text{ pF} \\ & \text{R}_{\text{L}} = 1000 \Omega \end{aligned}$		8.7	12.3		14.0		16.5	ns			
		$V_{CC} = 5.0 \pm 0.5 \text{ V C}_{L} = 50 \text{ pF}$ $R_{L} = 1000 \Omega$		5.8	7.9		9.0		11.0				
C _{IN}	Maximum Input Capacitance			6.0	10		10		10	pF			

		Typical @ 25°C, V _{CC} = 5.0 V	
C _{PD}	Power Dissipation Capacitance (Note 4)	18	pF

^{4.} C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no–load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.



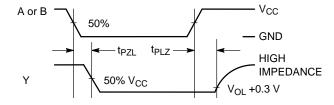
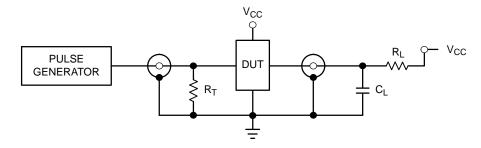


Figure 3. Output Voltage Mismatch Application

Figure 4. Switching Waveforms

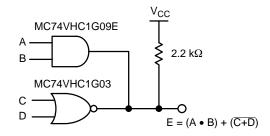


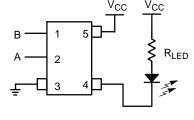
C_L = 50 pF equivalent (Includes jig and probe capacitance)

 $R_L = 1000 \Omega$ or equivalent

 $R_T = Z_{OUT}$ of pulse generator (typically 50 Ω)

Figure 5. Test Circuit





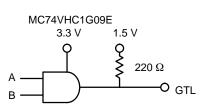


Figure 6. Complex Boolean Functions

Figure 7. LED Driver

Figure 8. GTL Driver

ORDERING INFORMATION

Device	Package	Shipping [†]
MC74VHC1G09EDFT2G	SC70-5 / SC-88A / SOT-353 (Pb-Free)	3000/Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

SC-88A (SC-70-5/SOT-353) CASE 419A-02

NOTES

BURRS.

DIM

D

G

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1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH

INCHES

MIN MAX

0.045 0.053

0.004 0.012

0.026 BSC

0.004 0.012

0.008 REF

0.079 0.087

0.087

0.004

0.071

0.031 0.043

0.004 0.010

419A-01 OBSOLETE. NEW STANDARD 419A-02. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE

MILLIMETERS

MIN MAX

0.10 0.30

0.10

0.65 BSC

0.20 REF

1 80 2.20 1.35

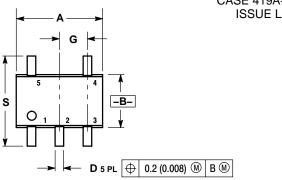
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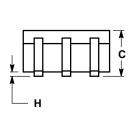
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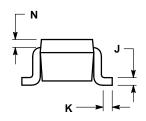
0.10

0.10 0.30

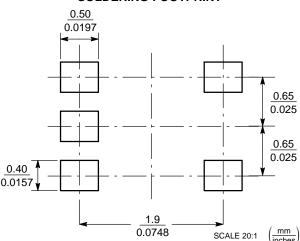
2.00







SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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